

### Vishay High Power Products

## **HEXFRED® Ultrafast Soft Recovery Diode, 210 A**







HALF-PAK (D-67)

cathode

PRODUCT SUMMARY				
I <sub>F</sub> (maximum)	210 A			
$V_{R}$	400 V			
I <sub>F(DC)</sub> at T <sub>C</sub>	106 A at 100 °C			

#### **FEATURES**

- · Very low Q<sub>rr</sub> and t<sub>rr</sub>
- · Lead (Pb)-free
- · Designed and qualified for industrial level



#### **BENEFITS**

- · Reduced RFI and EMI
- · Reduced snubbing

#### **DESCRIPTION**

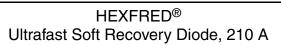
HEXFRED® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and dl/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	$V_R$		400	V
Continuous forward current	ı	T <sub>C</sub> = 25 °C	210	
Continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	106	Α
Single pulse forward current	I <sub>FSM</sub>	Limited by junction temperature	600	
Non-repetitive avalanche energy	E <sub>AS</sub>	$L = 100  \mu H$ , duty cycle limited by maximum $T_J$	1.4	mJ
Maximum power dissipation	$P_{D}$	T <sub>C</sub> = 25 °C	329	
Maximum power dissipation		T <sub>C</sub> = 100 °C	132	W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		400	-	-	
Maximum forward voltage		I <sub>F</sub> = 90 A		=	1.06	1.45	V
	V <sub>FM</sub>	I <sub>F</sub> = 180 A	See fig. 1	-	1.2	1.67	
		I <sub>F</sub> = 90 A, T <sub>J</sub> = 125 °C		-	0.96	1.23	
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 400 V	See fig. 2	-	0.6	2	mA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V See fig. 3		=	180	260	pF
Series inductance	L <sub>S</sub>	From top of terminal hole to mounting plane		-	7.0	-	nH

## HFA90NH40PbF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	90	140	ne
See fig. 5		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 90 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	158	240	ns
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	9	17	А
See fig. 6		T <sub>J</sub> = 125 °C		-	15	30	
Reverse recovery charge	arge Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	420	1100	nC
See fig. 7		T <sub>J</sub> = 125 °C		-	1200	3200	IIC
Peak rate of recovery current See fig. 8 dl <sub>(rec)M</sub> /dt	dl/dt	T <sub>J</sub> = 25 °C		-	370	=	Δ/μο
	T <sub>J</sub> = 125 °C		-	270	=	A/μs	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 150	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub> DC operation See fig. 4		0.38	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	0.05	
Approximate weight				30	g
Approximate weight				1.06	oz.
Mounting torque	minimum		Non-lubricated threads	3 (26.5)	
Mounting torque — maxin				4 (35.4)	N⋅m
Terminal torque ——	minimum			3.4 (30)	(lbf · in)
	maximum			5 (44.2)	
Case style			HALF-PAK module		•





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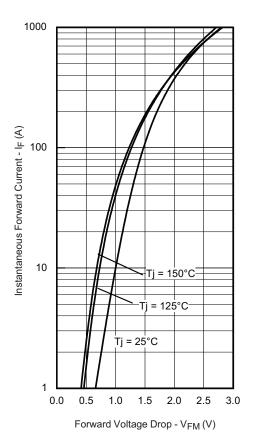


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

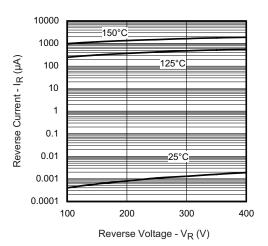


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

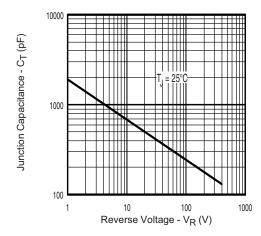


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

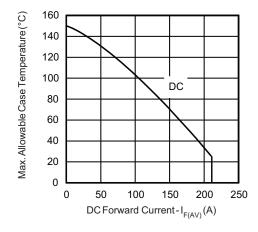


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current

### HFA90NH40PbF

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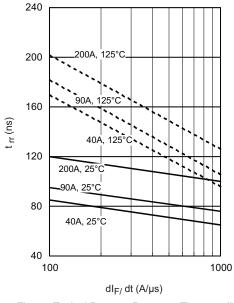


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

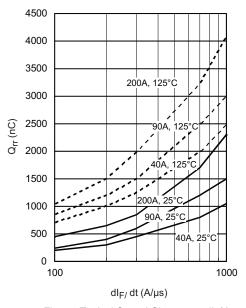


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

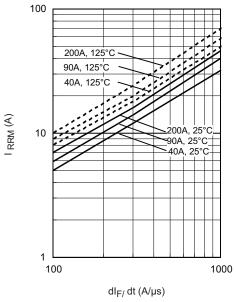


Fig. 6- Typical Recovery Current vs. dI<sub>F</sub>/dt

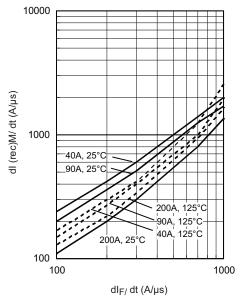


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$ 



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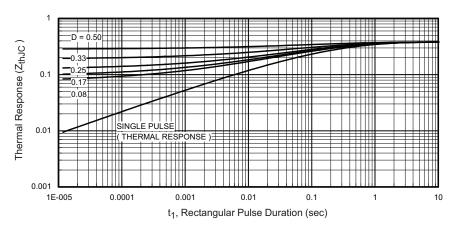


Fig. 9 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

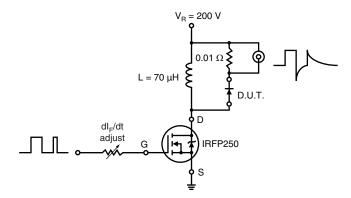
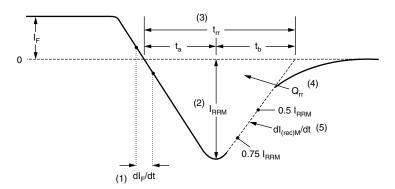


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$ 
  - $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (5)  $dl_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 11 - Reverse Recovery Waveform and Definitions

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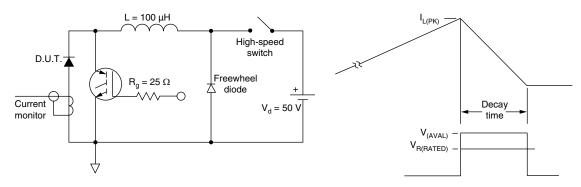


Fig. 12 - Avalanche Test Circuit and Waveforms

### **ORDERING INFORMATION TABLE**

Device code **HFA** 90 40 **PbF** Ν Н (2) (3) (4) (5) (6)- HEXFRED® family - Average current rating - N = Not isolated - H = HALF-PAK

5 - Voltage rating (400 V)

6 - Lead (Pb)-free

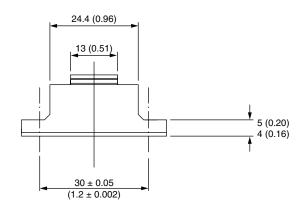
LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95020		

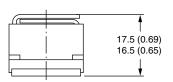


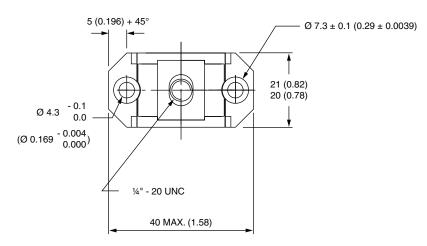
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### **D-67 HALF-PAK**

### **DIMENSIONS** in millimeters (inches)









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